

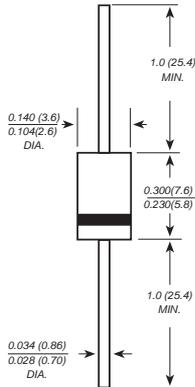


SR220 THRU SR2200

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 2.0 Ampere

DO-15



Dimensions in inches and (millimeters)

FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-15 molded plastic body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.014 ounce, 0.40 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SR 220	SR 230	SR 240	SR 250	SR 260	SR 270	SR 280	SR 290	SR 2A0	SR 2150	SR 2200	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	70	80	90	100	150	200	VOLTS
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	49	56	63	70	105	140	VOLTS
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	70	80	90	100	100	200	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1)	I_{AV}	2.0											Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	60.0											Amps
Maximum instantaneous forward voltage at 2.0A	V_F	0.55		0.70		0.85			0.95				Volts
Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$ $T_A=100^\circ\text{C}$	I_R	0.5					0.2			2.0		mA	
Typical junction capacitance (NOTE 1)	C_J	220			80								pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0											°C/W
Operating junction temperature range	T_J	-50 to +125					-50 to +150						°C
Storage temperature range	T_{STG}	-50 to +150											°C

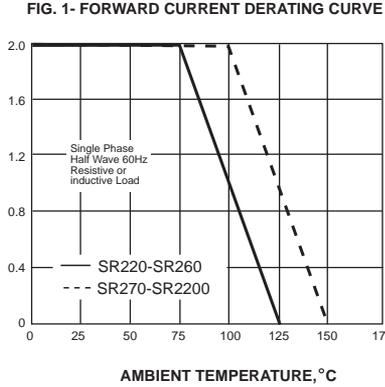
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

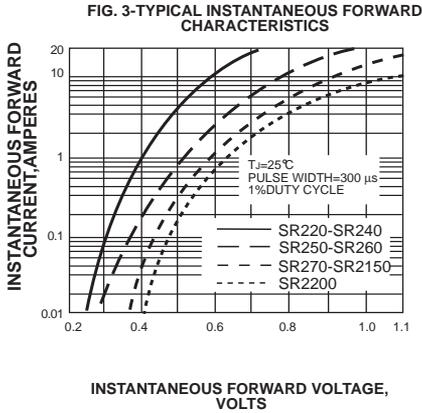
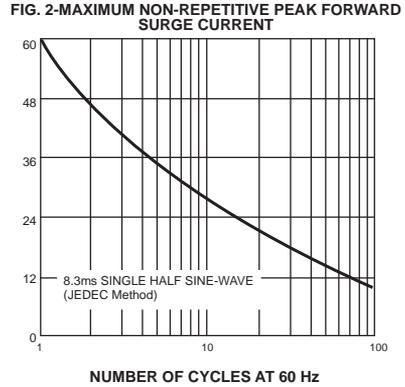


RATINGS AND CHARACTERISTIC CURVES SR220 THRU SR2200

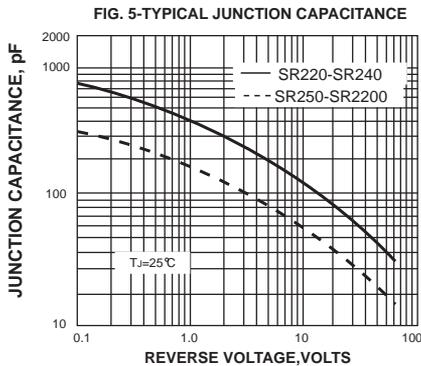
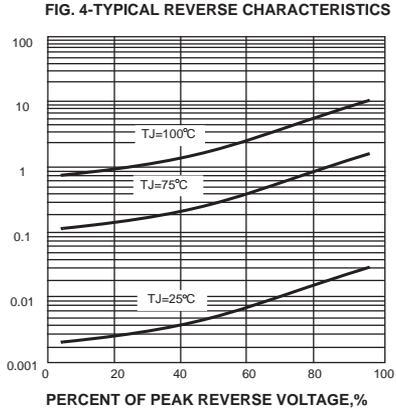
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



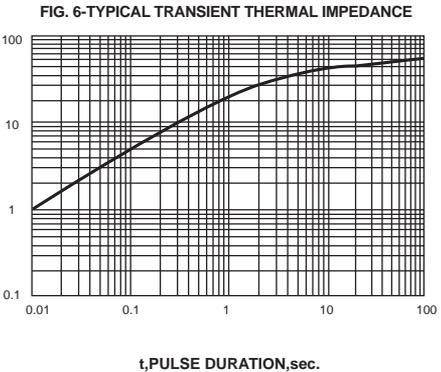
PEAK FORWARD SURGE CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES



TRANSIENT THERMAL IMPEDANCE, °C/W



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考!)



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